

New Product DATA SHEET

MR Sensor

MRUS51S

Micro power Built-in IC ultra-minimum MR sensor

1.FEATURES

High-sensitivity (1.5mT(typ.)) & Ultra-minimum Size & Low source supply

*Micro power (6µW(typ):Vcc=1.8V)

1.Dimension (Unit:mm)

(suited for battery-operation)

*Ultra-small size

MR(Magneto-resistance)sensor

- Volume and mounting area are 70% smaller than MRSS22L.
- * Height is about 50 % lower than MRSS22L.

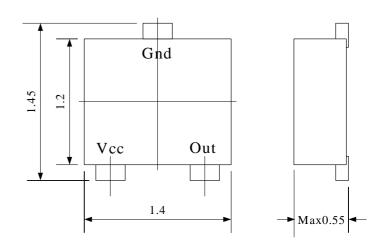
*Operating in one way magnetic field

*Operating with independent pole

(easily manufacture)

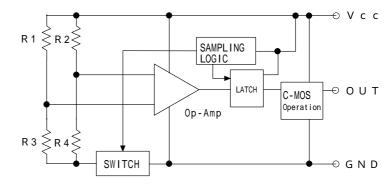
*Superior Temperature stability

*Lead free goods



2.Fundamental Operation

2-1.Direction of Magnetic Field



 $\text{R1} \sim \text{R4} : \text{MR Elements}$

2-3.Performance Characteristics (25+3 °C)

	Operating require Condition	Output Voltage
When power switch is ON	$H = 0 \ mT$ (Magnetic Flux Density)	Hi-level
When magnetic field is applied	H 2.2 mT (Magnetic Flux Density)	Lo-level
When magnetic field is applied	H 0.5 mT (Magnetic Flux Density)	Hi-level

2-2.Circuit Block



MRUS51S

3.Performance

3-1.Operating Conditions Recommended

(Ta = 25 + 3)	°C unless	otherwise	specified)

Item	Output	Condition	Min	Std	Max	Unit
Supply Voltage	-	-	1.6	1.8	3.5	V
Supply Current	-	Vcc=1.8V	-	3	-	μΑ
Ambient Temperature	-	-	-40	25	85	°C
Output Voltage	VOH	Vcc=1.8V Iout=1mA	1.6	-	-	V
Output voltage	VOL	VCC=1.8V Iout=-1mA	-	-	0.2	V
Operating Magnetic	Hi-level output Hon	25 <u>+</u> 3°C	-	1.5 (1.4)	2.2 (1.8)	mT ^{(*1}
Field	Lo-level output Hoff	25 <u>+</u> 3°C	0.5 (0.4)	-	-	(kA/m)

^{*1)} 1 [mT](SI) = 10 [G] (CGS)

3-2. Absolute Maximum Ratings

(Ta = 25 ± 3 C° unless otherwise specified)

Item	Condition	Specifications	Unit
Supply Voltage	-	6.0	v
Storage Temperature	-	-40 ~ +125	°C

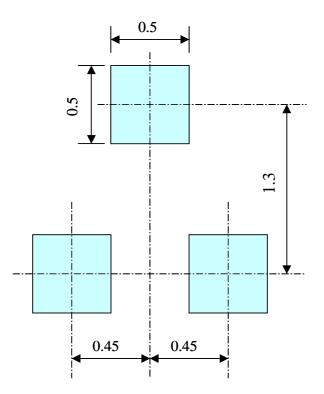
The products and product specifications described in this material are subject to change without notice for reasons of modification or improvement.



MR Sensor

MRUS51S

3-3. Recommended mounting Pad



Unit(mm)

The products and product specifications described in this material are subject to change without notice for reasons of modification or improvement.



NEC Corporation Fiber Optic Device Division (Shin Tamachi Building) 34-6, Shiba 5-chome, Minato-ku, Tokyo 108-0014, Japan Tel:+81-3-3798-5864 Fax:+81-3-3798-5857

EWV-19-0087-01E, Feb., 2005 Copyright © 2005 NEC Corporation

http://www.sw.nec.co.jp/on/dd/en/